

Apse13D_TC chip characterization

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Outline

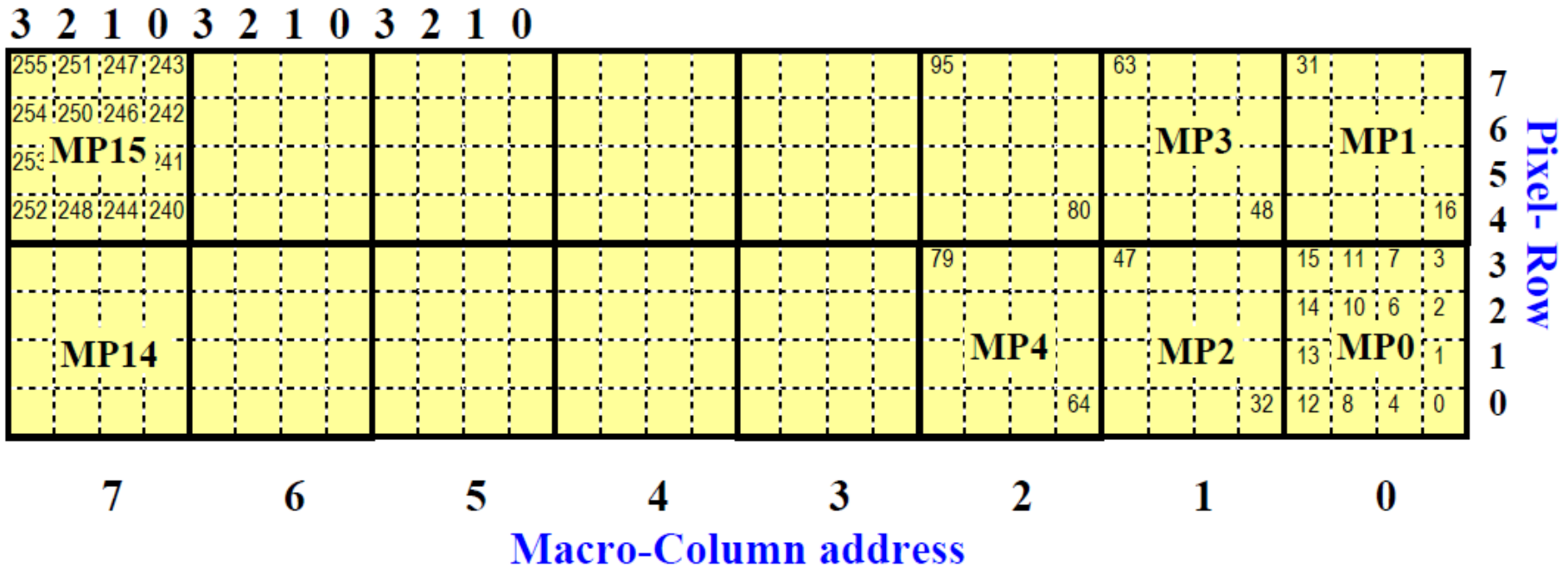
- **Noise scans**
 - Chip5
 - Chip6

- **Differential spectrum with the Fe55 source**
 - Chip5
 - Chip6

ApSel3D_TC matrix layout

- Matrix with 8 (rows) x32 (columns) = 256 pixels
- Matrix is divided in macro-pixels (MP) 4x4 pixels => 16 MP
- Can enable some MP and mask others

Pixel-Column inside a MC/MP



Noise scans: the fit function

- Previously used a physics motivated function to describe the occupancies of the noise scans

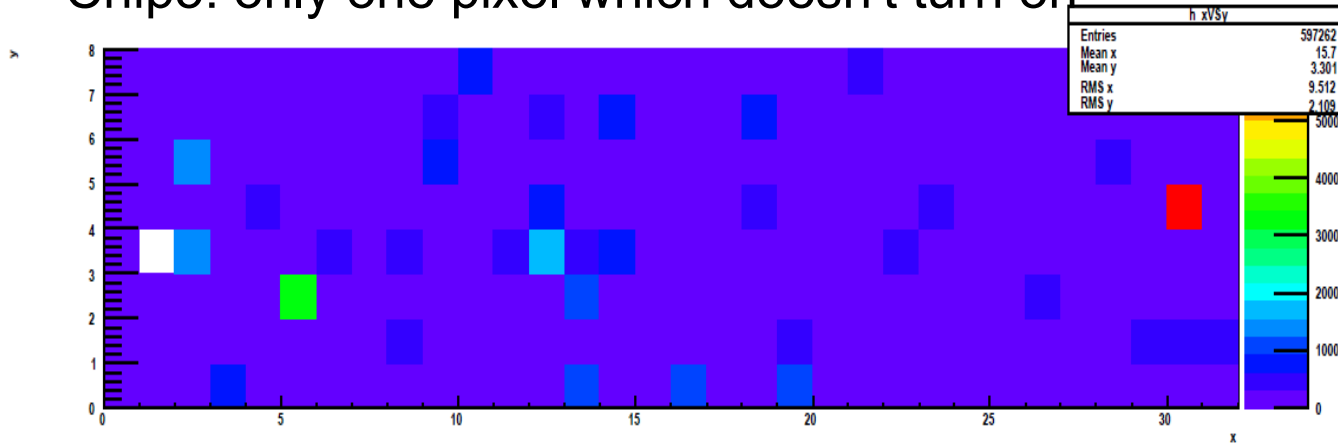
$$\text{Occupancy} = 1.0 - \exp\{-v_0 t_{\text{obs}} \exp(-(\text{thr} - \mu)^2/2\sigma^2)\}$$

- Where, σ is the noise, the μ baseline, v_0 the fire rate at zero threshold, t_{obs} the observation time. This expression is only valid if $t_{\text{obs}} \gg$ worst death-time. We used $t_{\text{obs}} = 2\text{ms}$ (worst death time $\sim 4*50\text{ns}*16 = 3.2\mu\text{s}$).
- Using this function a significant fraction of the fits didn't converge ($\sim 28\%$ for chip-5)
- Decided to use an asymmetric function with a different $\sigma(\mu)$ to the left/right of μ . $\sigma(\mu) = \sigma_L$ (σ_R) for $\text{thr} - \mu < 0$ ($\text{thr} - \mu > 0$)
- With this function the failed fit reduces significantly ($\sim 12.8\%$ for chip-5)
- The noise scan fits are used to extract the pixel base-line, which will be used to estimate the gain from Fe55 spectra

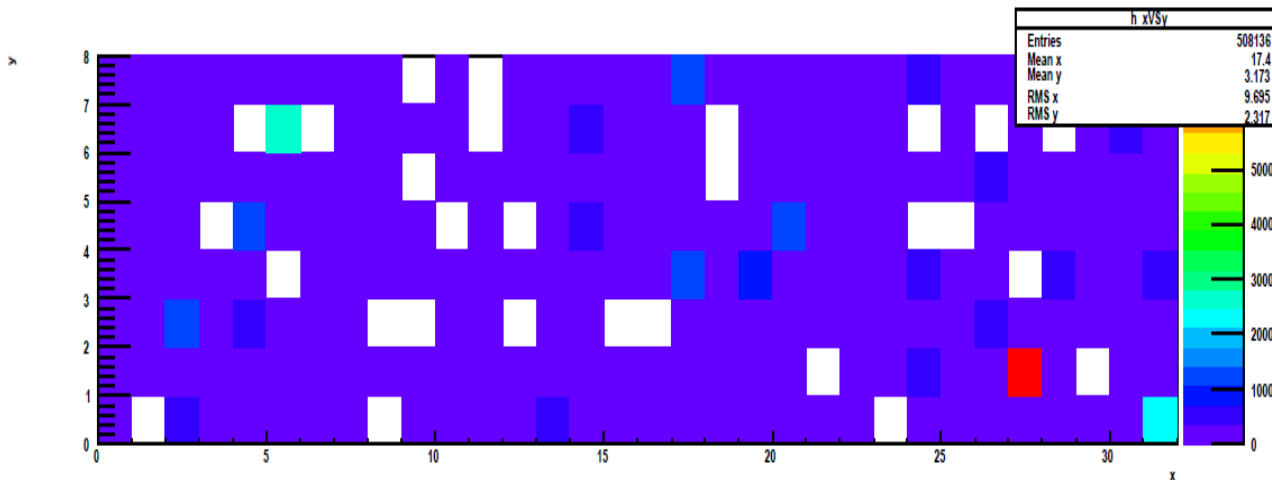
Noise scans: Chip5 and Chip6

- Performed noise scans from 1250 up to 1500 DAC (100 steps of 4 DAC) with $t_{\text{obs}} = 2\text{ms}$

- Chip5: only one pixel which doesn't turn on



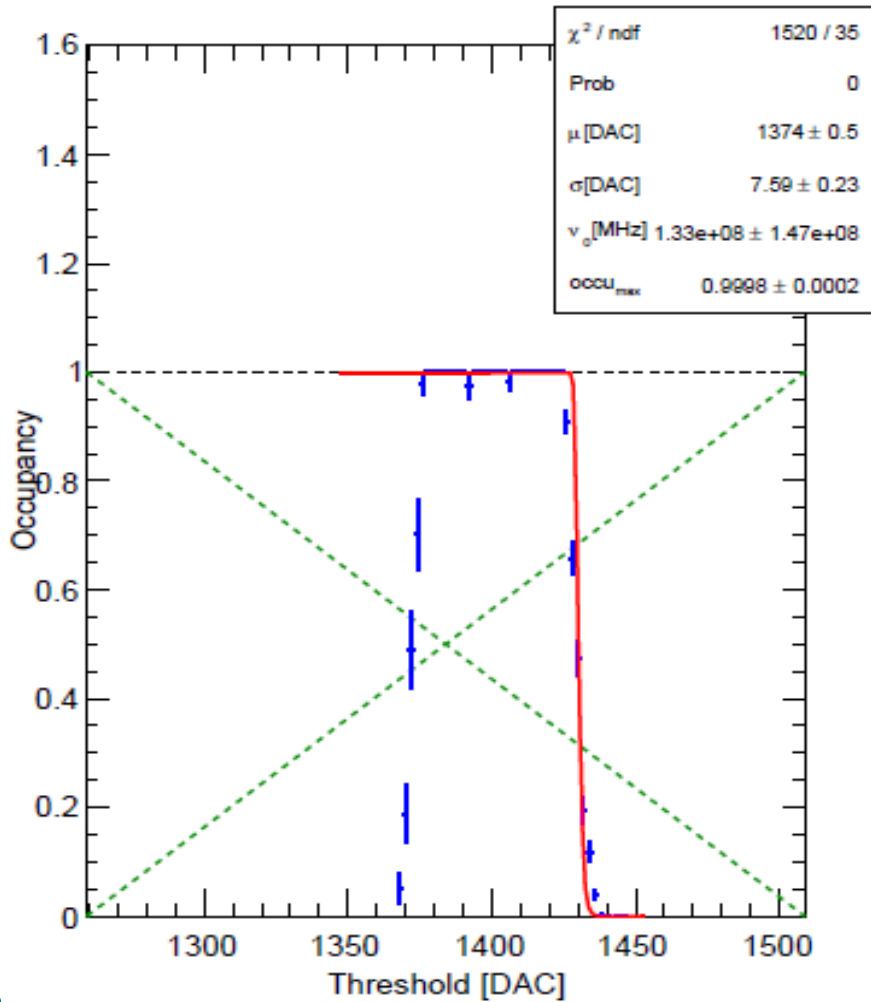
- Chip6: a significant amount of dead pixels (28 \Rightarrow 11%)



Noise fit: Chip5

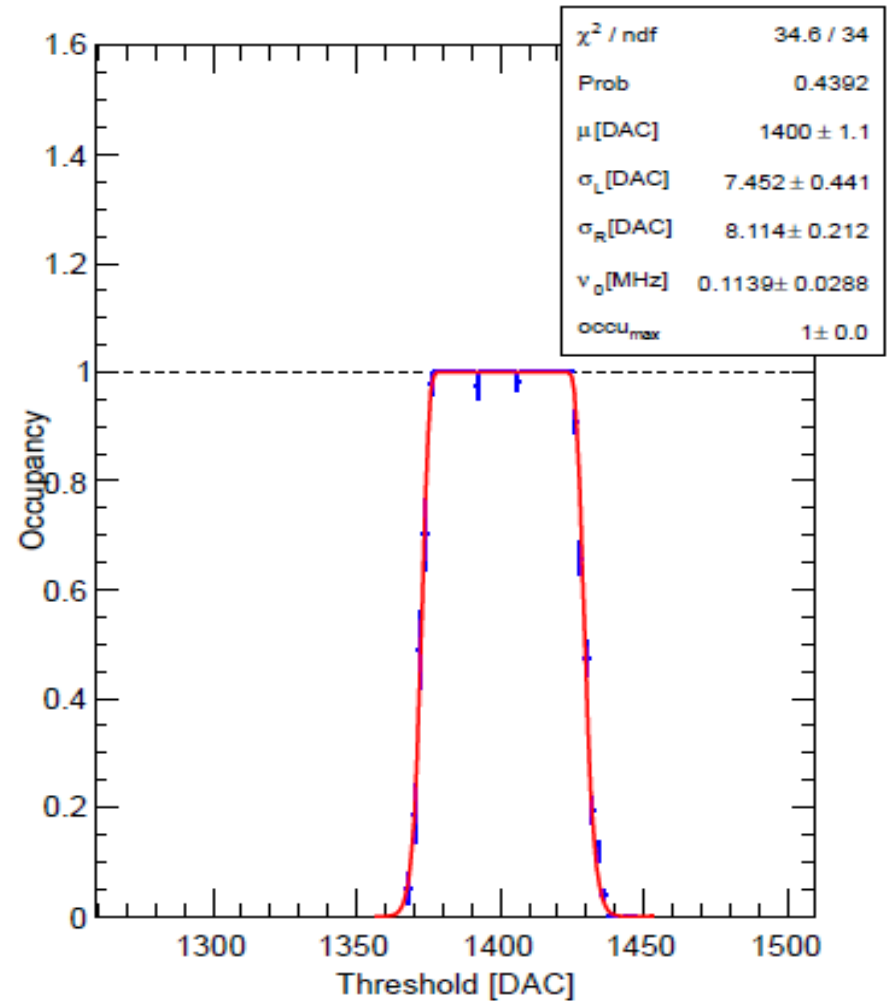
Symmetric fit

occupancy for pixel (30,0) (symmetric fit)



Asymmetric fit

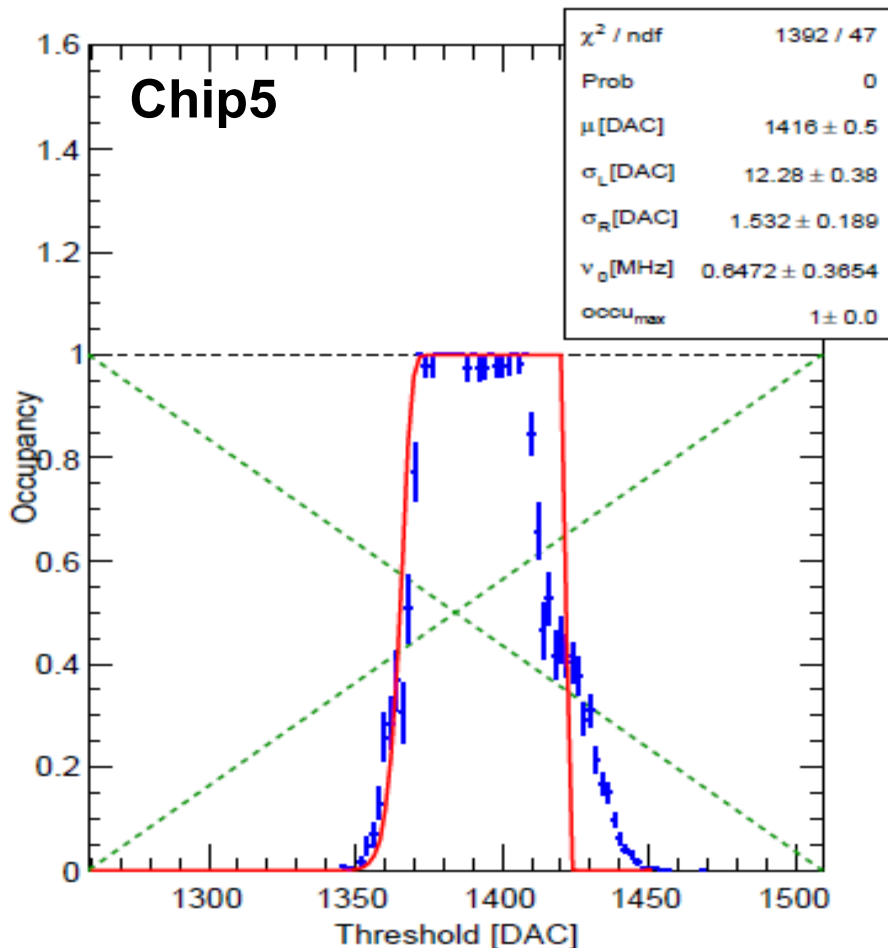
occupancy for pixel (30,0) (asymmetric fit)



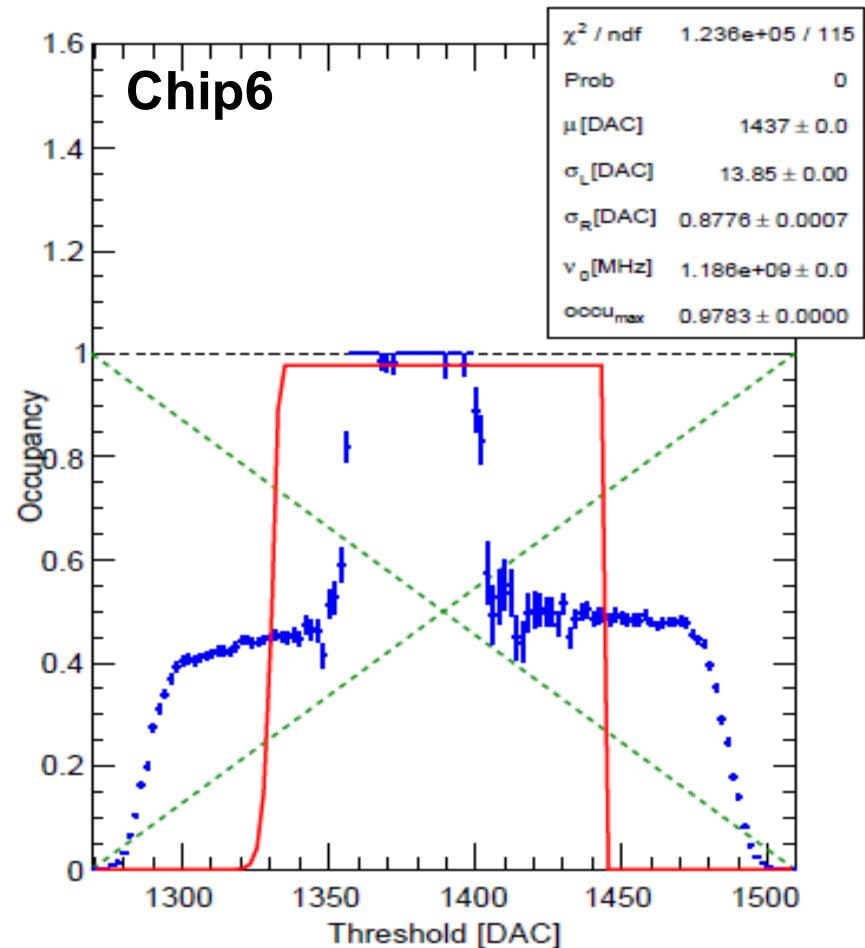
Noise scans: Chip5 and Chip6

- Some pixels for both chips show strange features
- The fit poorly converges in those cases

occupancy for pixel (15,1) (asymmetric fit)

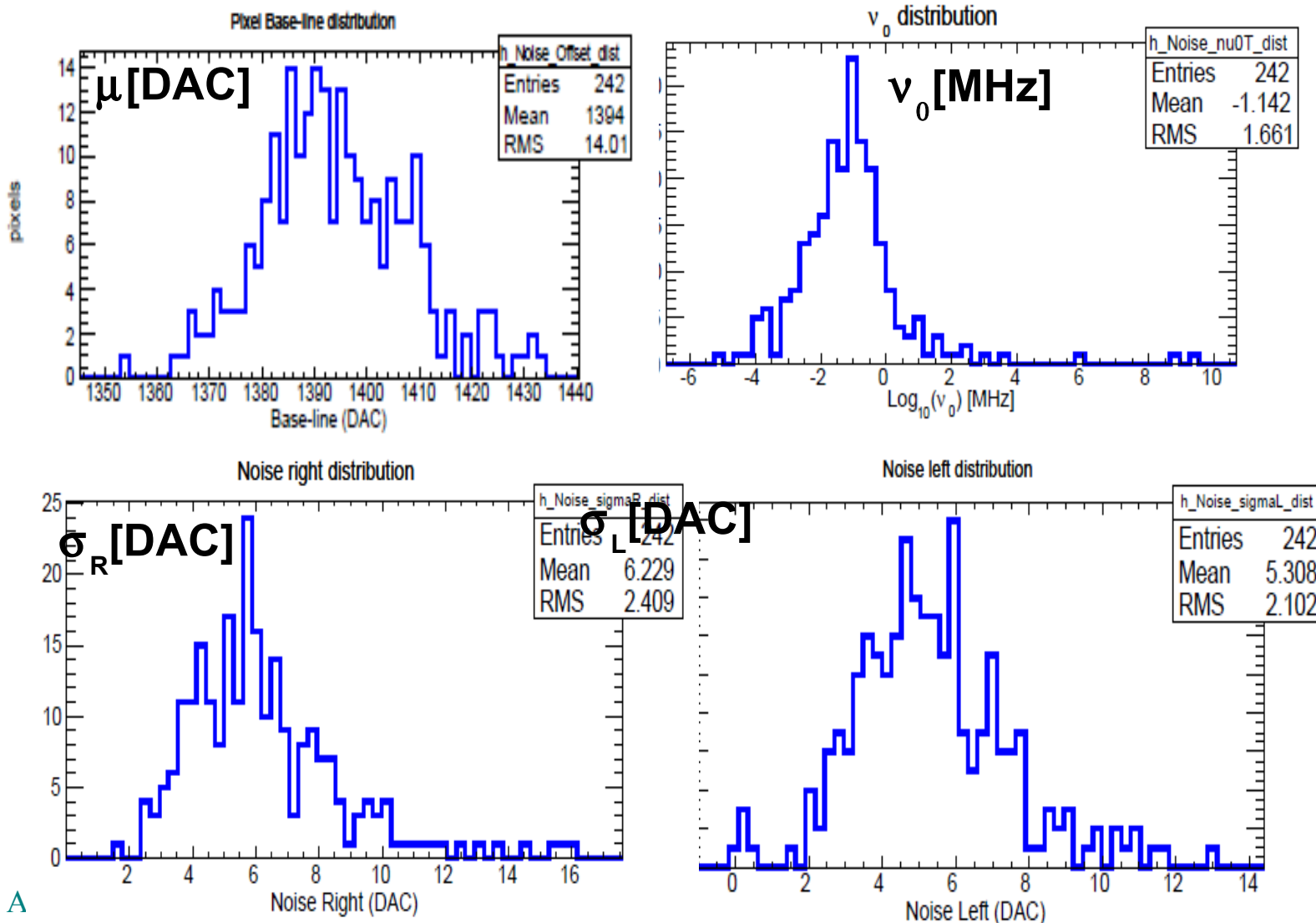


occupancy for pixel (27,1) (asymmetric fit)



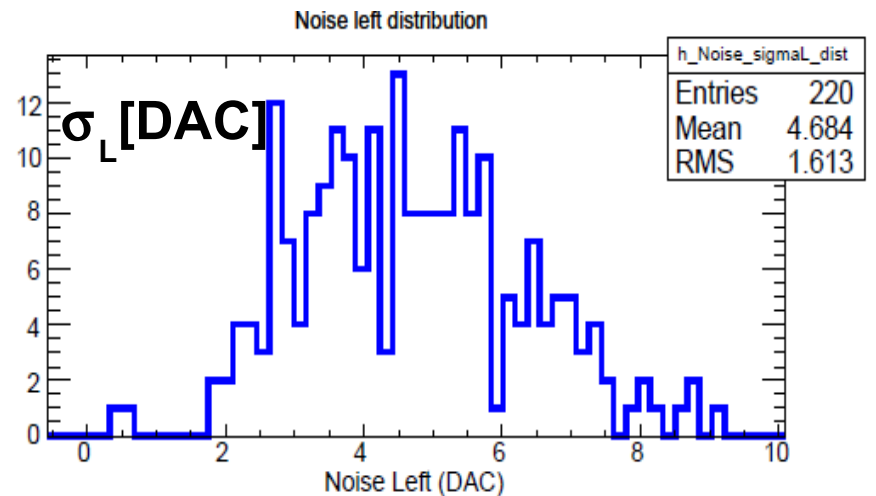
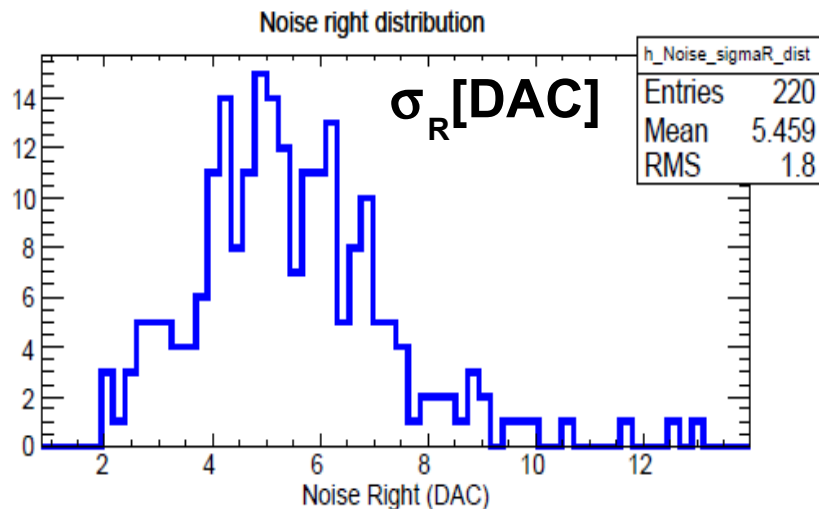
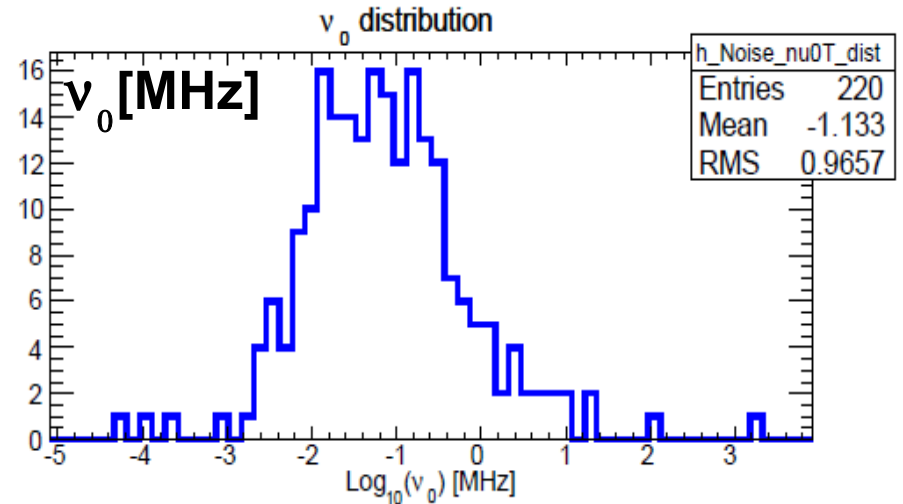
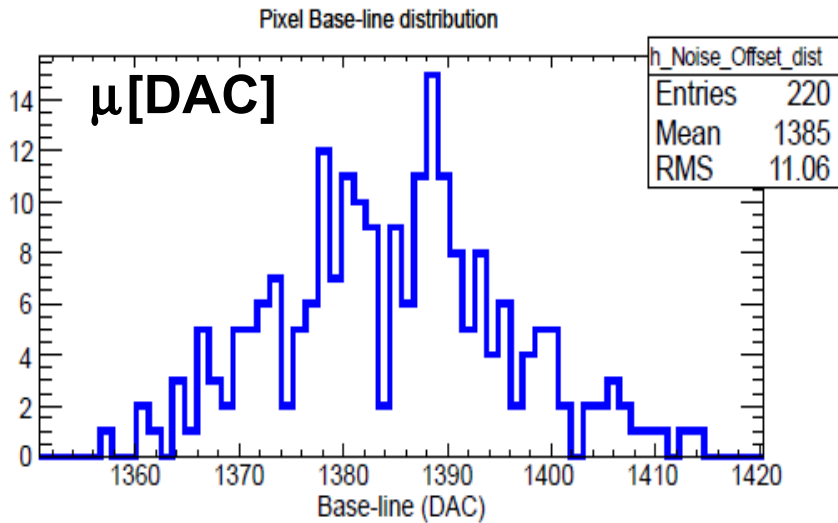
Noise scans: Chip5

In some cases the fit doesn't converge properly. Those pixels are not used for the plots below. 221 fits converged (there is 1 dead pixel).



Noise scans: Chip6

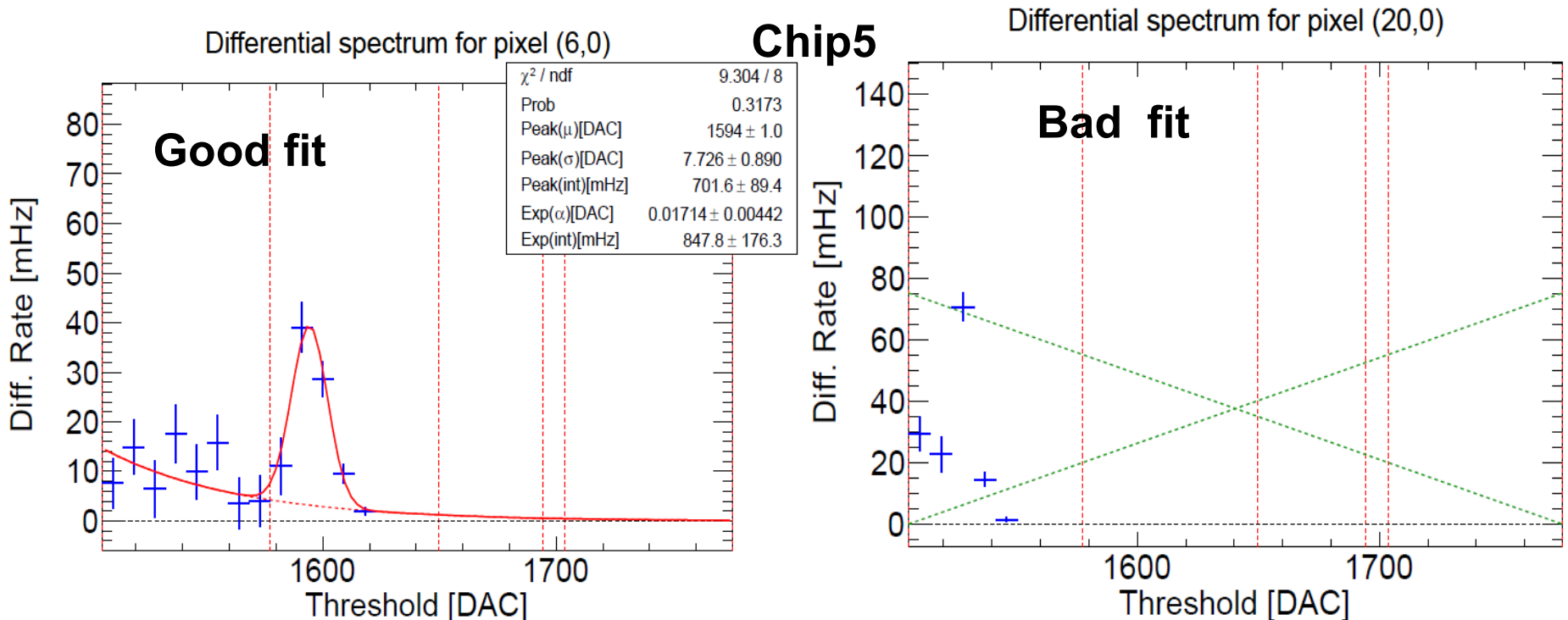
- In some cases the fit doesn't converge properly. Those pixels are not used for the plots below. 204 fits converged (there is 28 dead pixel).



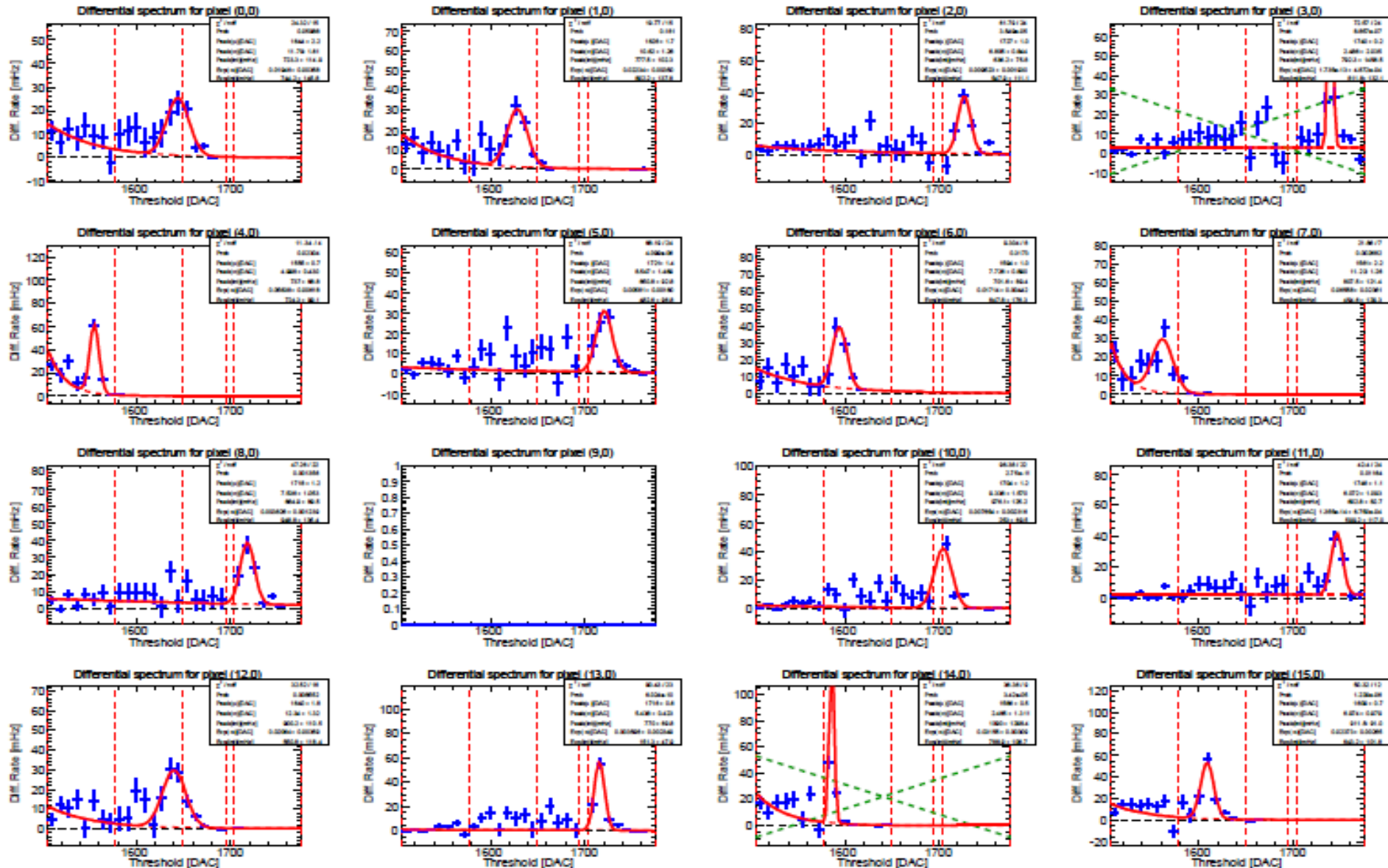
Data-taking with Fe55 source

Data with Fe55 source

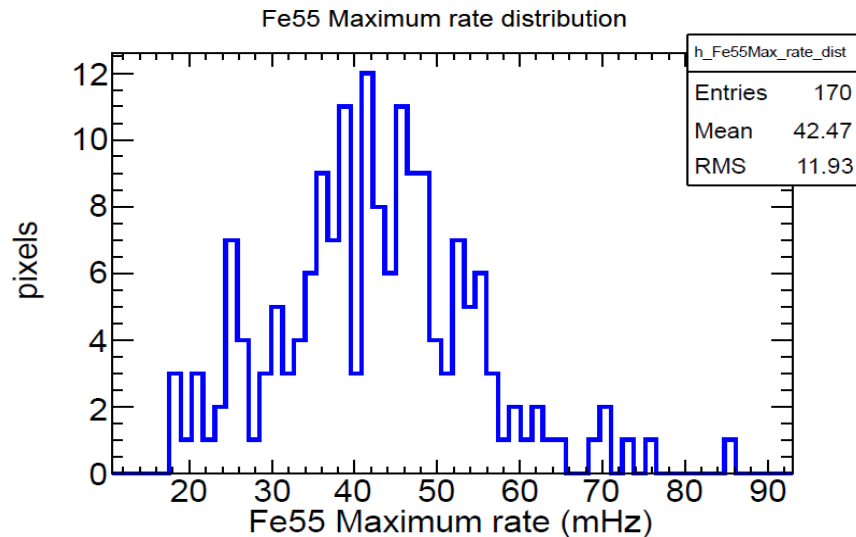
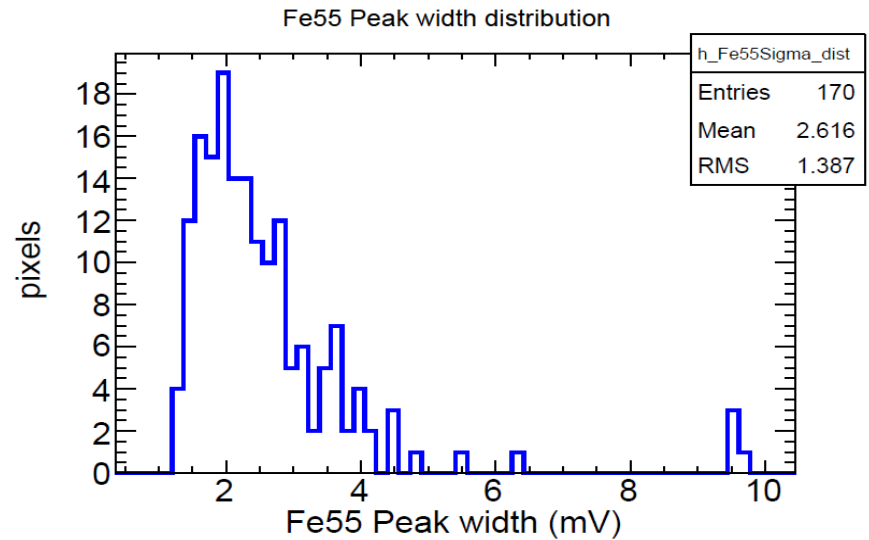
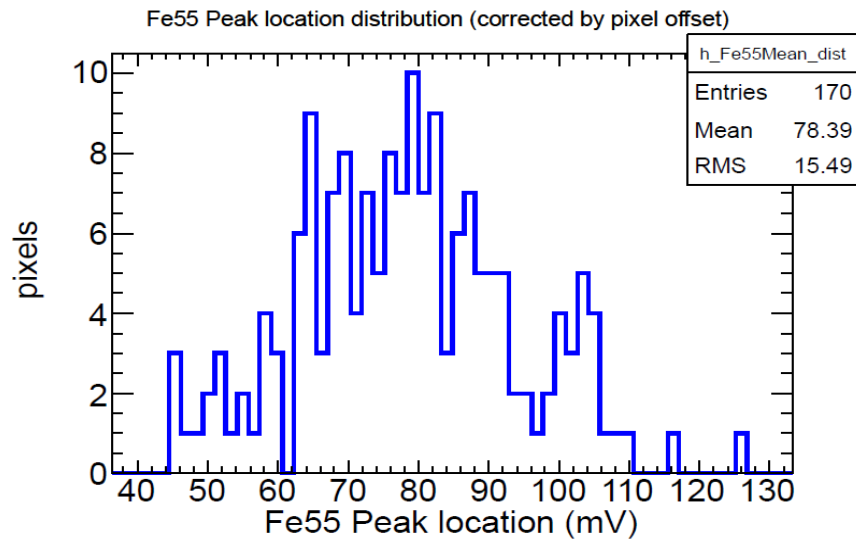
- With the Fe55 source took data varying the threshold,
 - Chip5: 1510 to 1780 in steps of 9 (units in DAC)
 - Chip6: 1591 to 1789 in steps of 9
- Out of the integral spectrum calculated the differential spectrum (bin_{i+1} – bin_i on the integral spectrum)
- Put together the differential spectrum of all the runs
- Tried to look for the Fe55 peak and fit it ⇒ Gaussian+exponential



Fe55 source: Chip5 fit example



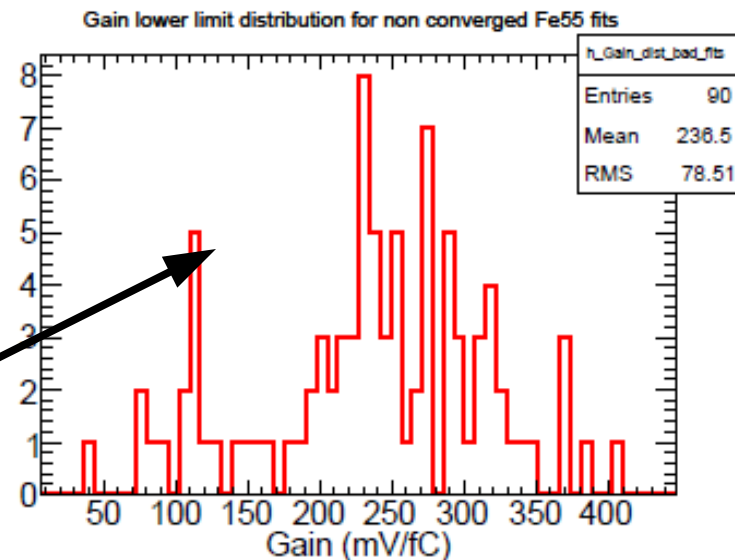
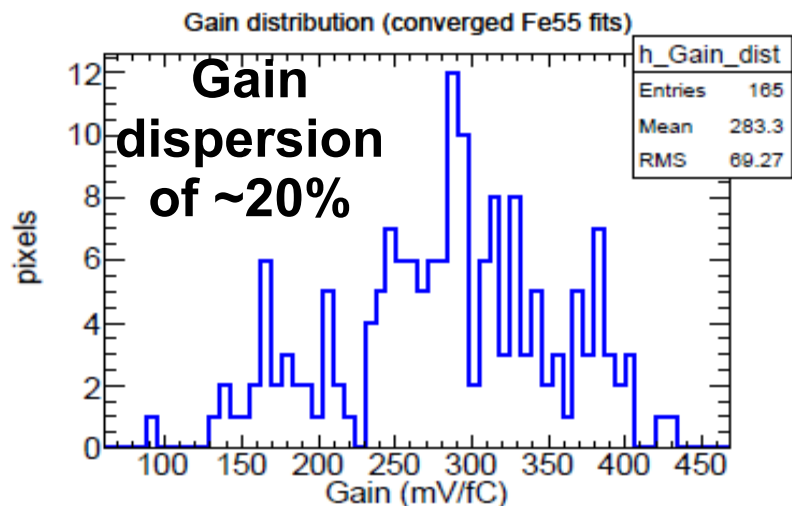
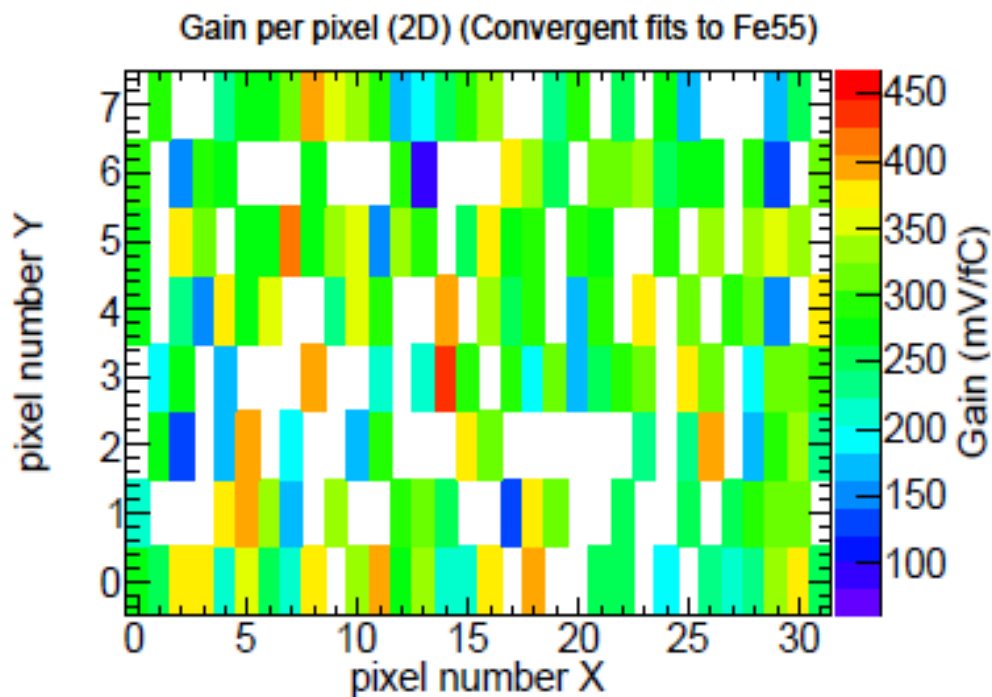
Fe55 source: Chip5 fit results



- Subtracted pixel base-line from peak mean
- Mean and width of the peak has been converted from DAC to mV

Fe55 source: Chip5 the gain

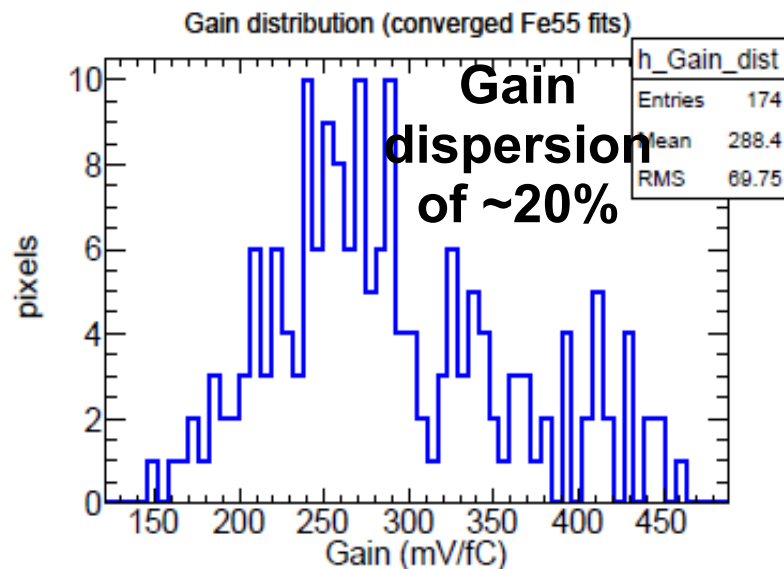
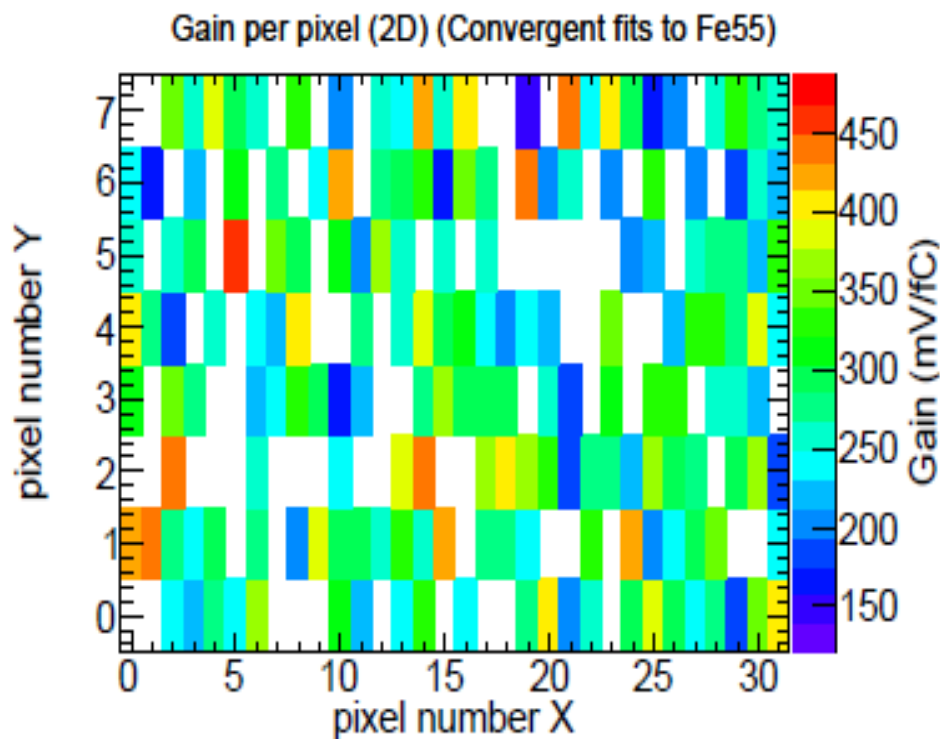
- Use the peak base-line subtracted mean to estimate the gain
gain = mean/charge (charge = 1640 e⁻)



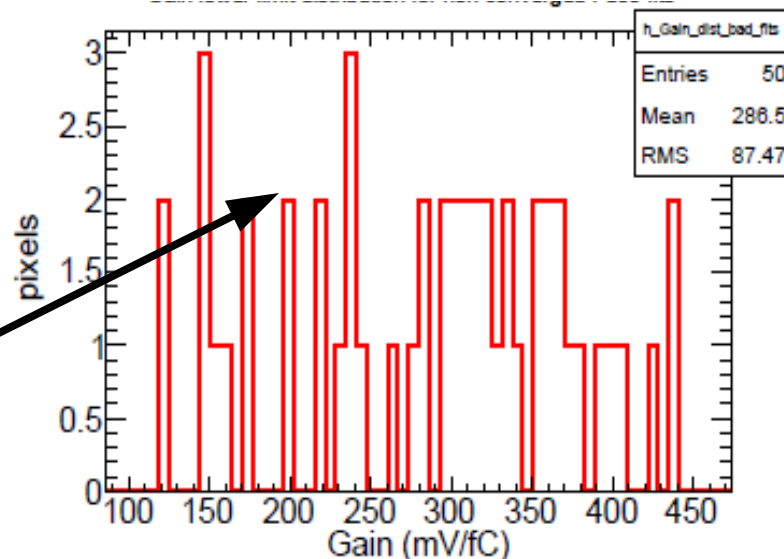
- For pixels for which the the fit doesn't converge estimate a lower-limit of the gain

Fe55 source: Chip6 the gain

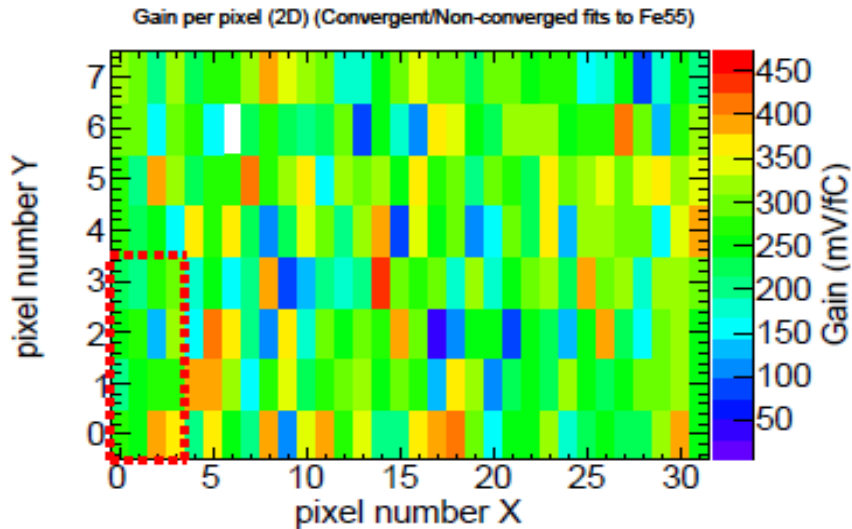
- Use the peak base-line subtracted mean to estimate the gain
gain = mean/charge (charge = 1640 e⁻)



- For pixels for which the the fit doesn't converge estimate a lower-limit of the gain



Trying to pilot the Apse13D_TC chips (Chip5)

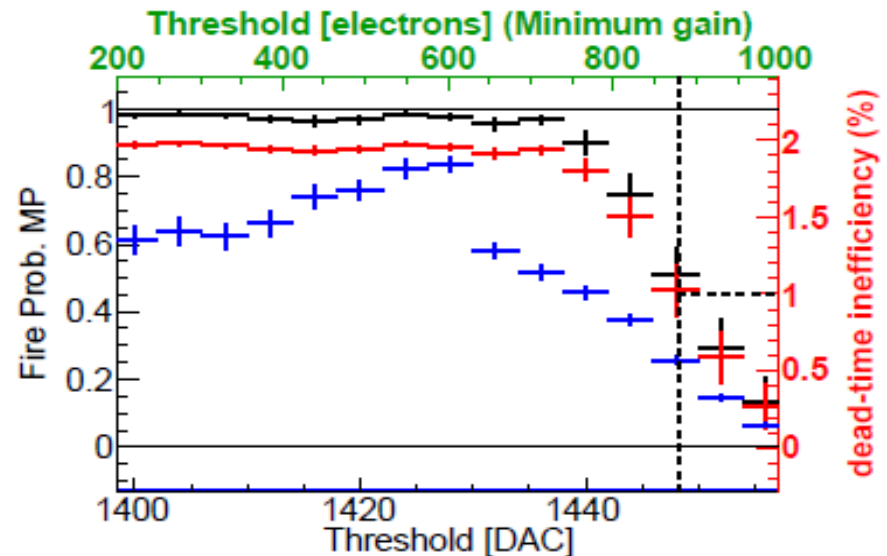
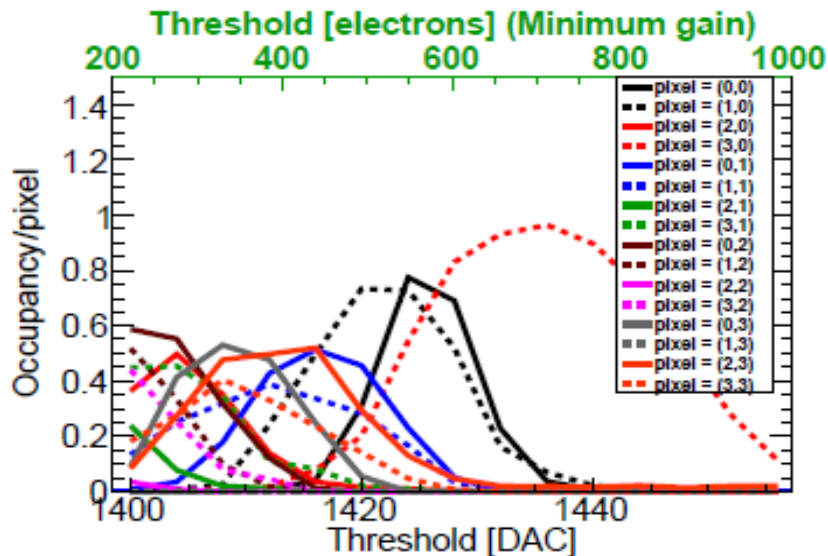
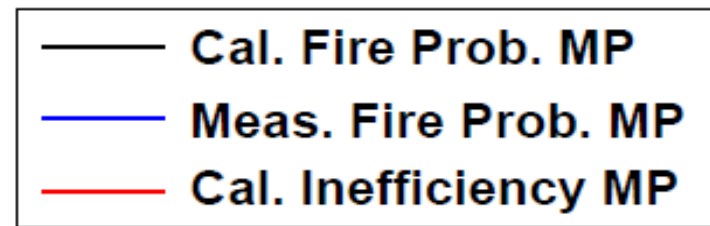


Macro Pixel (MP) 0

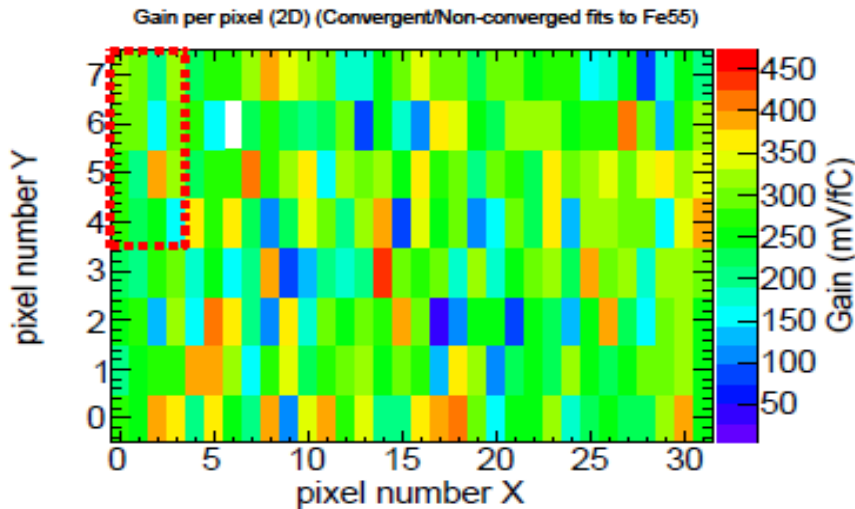
N. unused pixels = 0

Gain_{min} = 139.75 mV/fC

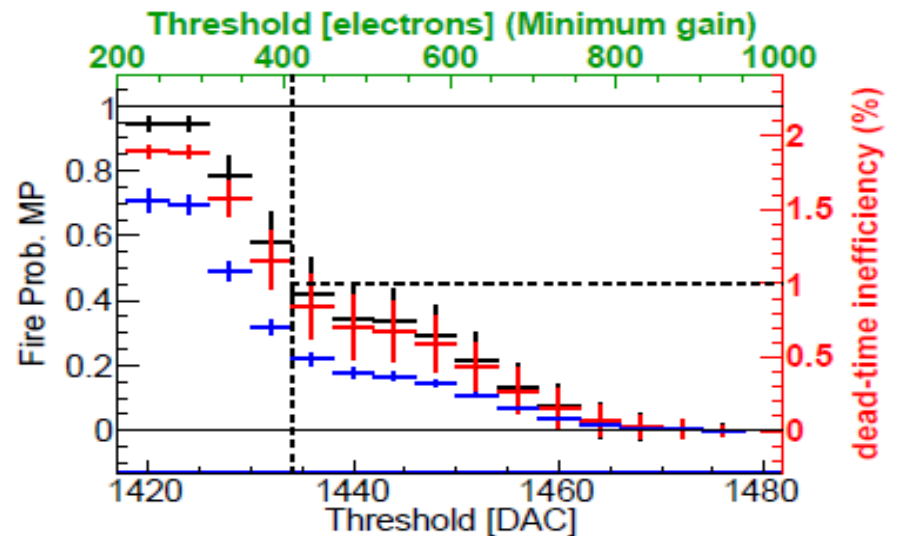
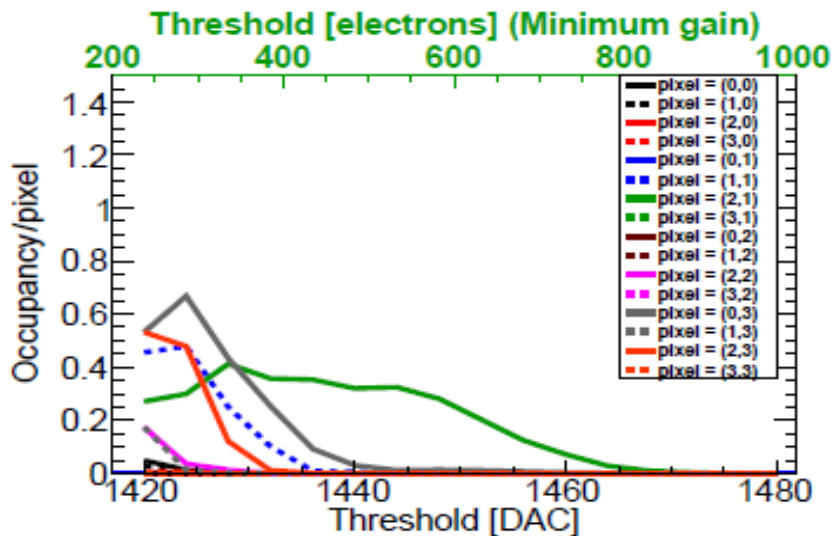
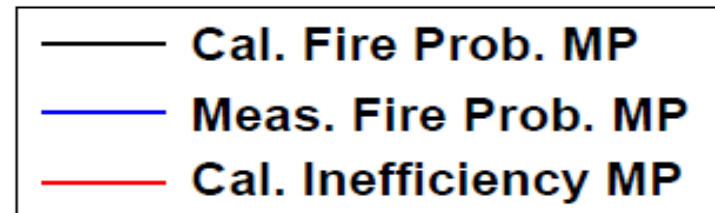
Gain_{max} = 381.98 mV/fC



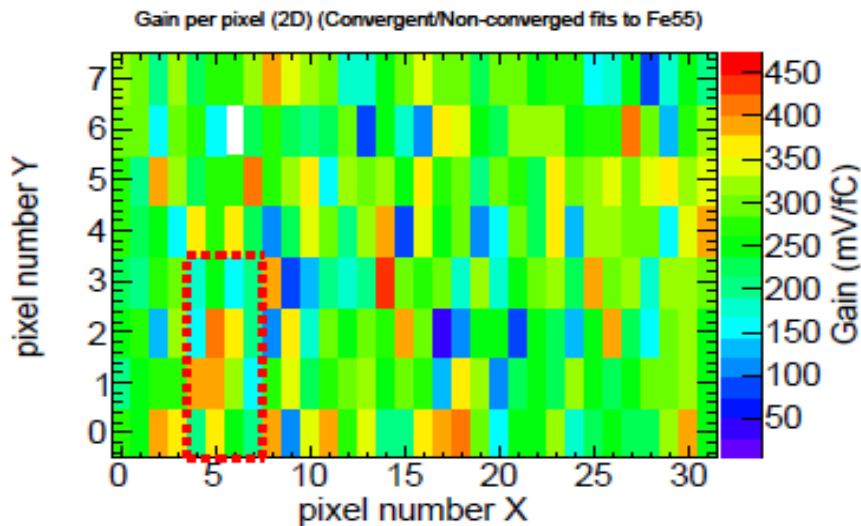
Trying to pilot the Apse13D_TC chips (Chip5)



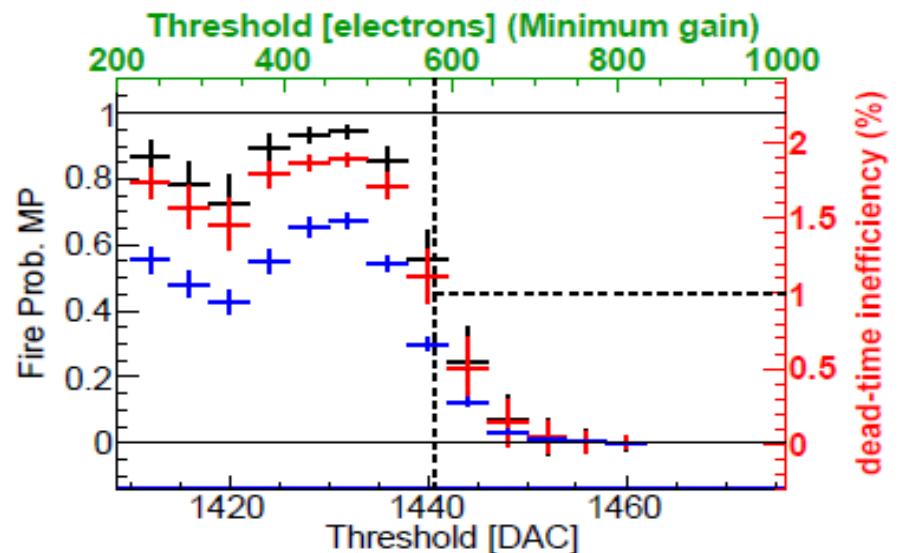
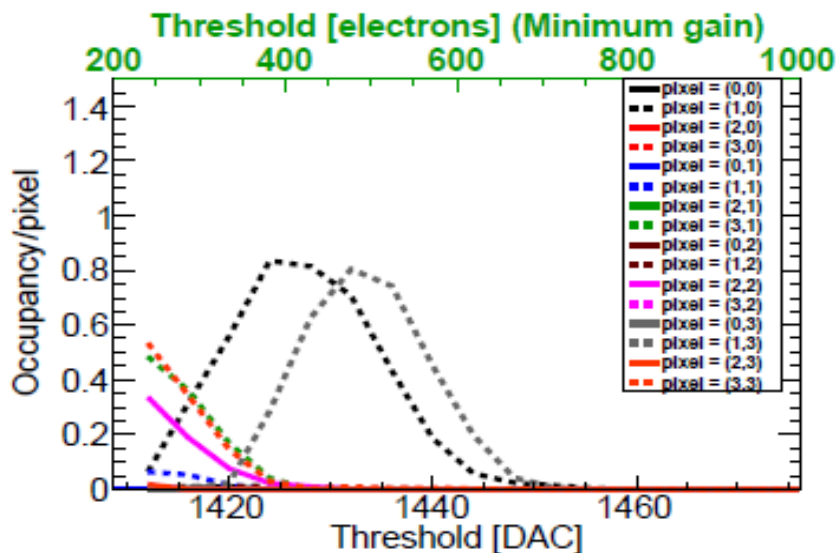
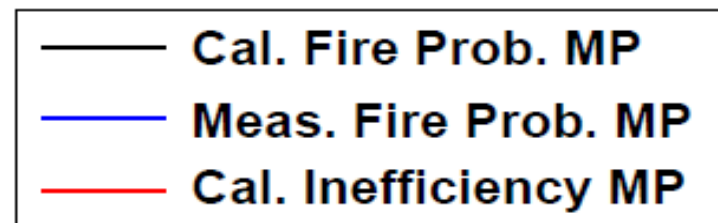
Macro Pixel (MP) 1
 N. unused pixels = 0
 $\text{Gain}_{\min} = 154.38 \text{ mV/fC}$
 $\text{Gain}_{\max} = 385.42 \text{ mV/fC}$



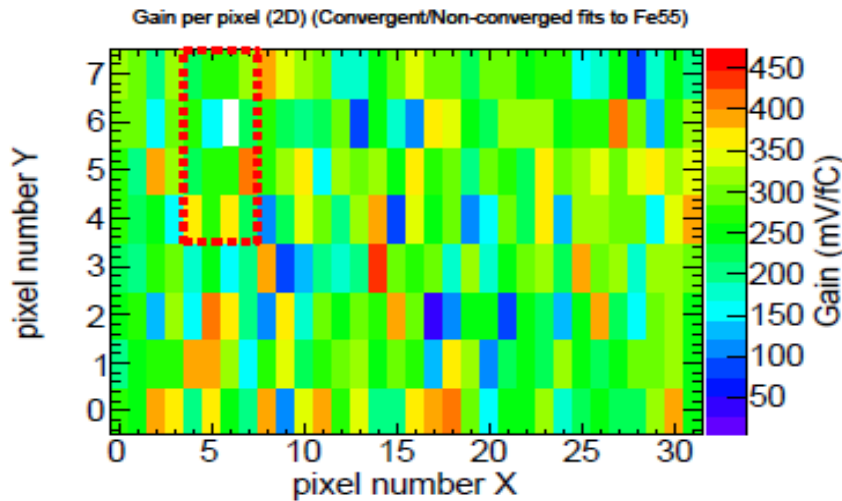
Trying to pilot the Apse13D_TC chips (Chip5)



Macro Pixel (MP) 2
 N. unused pixels = 0
 $\text{Gain}_{\min} = 160.69 \text{ mV/fC}$
 $\text{Gain}_{\max} = 404.20 \text{ mV/fC}$



Trying to pilot the Apse13D_TC chips (Chip5)

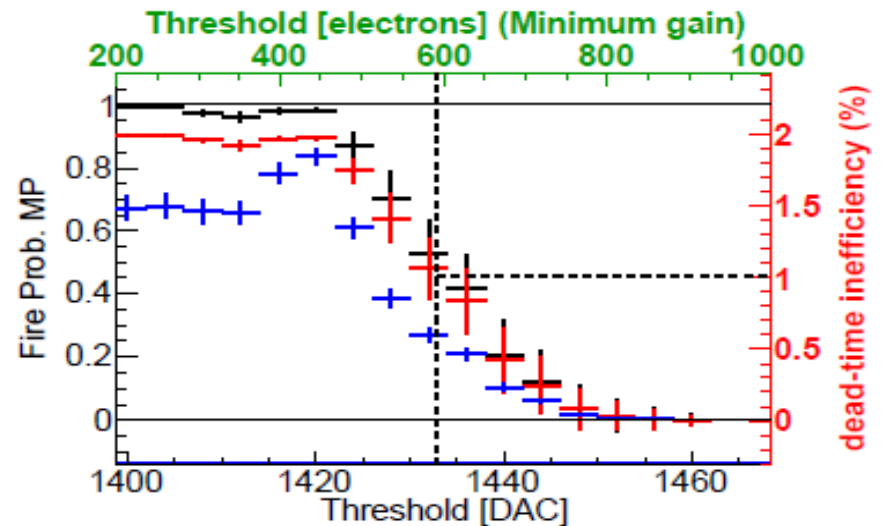
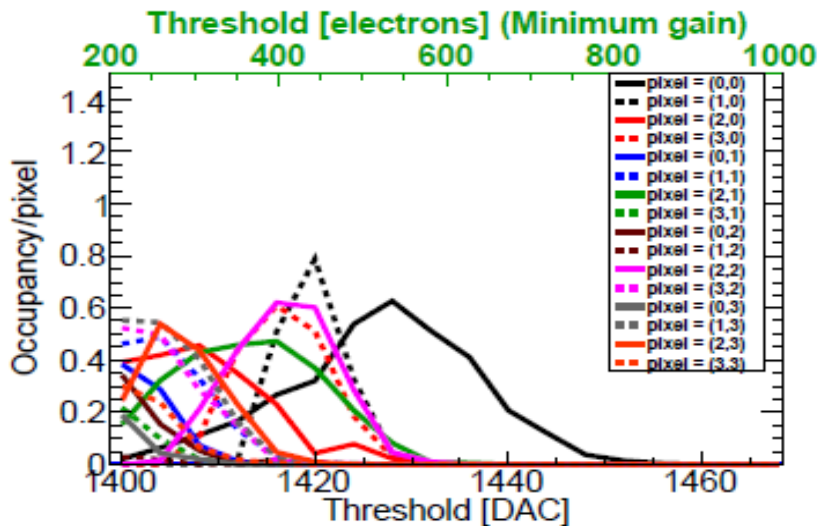
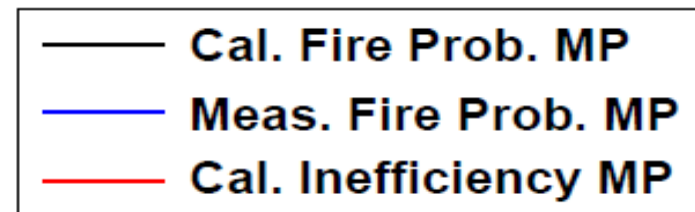


Macro Pixel (MP) 3

N. unused pixels = 1

Gain_{min} = 165.78 mV/fC

Gain_{max} = 420.32 mV/fC



Summary on Apse13D_TC

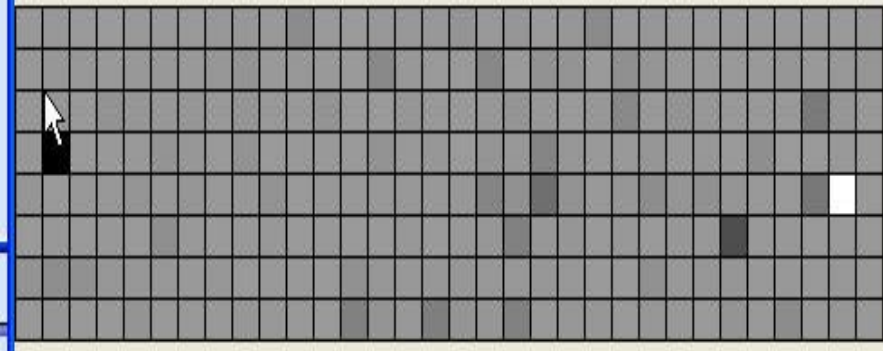
- Measurements with ^{55}Fe source show a significant variation of the gain inside the matrix
- Gain variation seems to be random: no evident structures inside the matrix
- Significant variation of the gain even within a MP
- All these features makes the Apse13D_TC chips difficult to pilot in a configuration with a reasonable efficiency

- The strategy for test-beam on November:
 - Main priority INMPS32x32
 - Put the chip on beam if some time available
 - Unfortunately had no time to take data with these chips

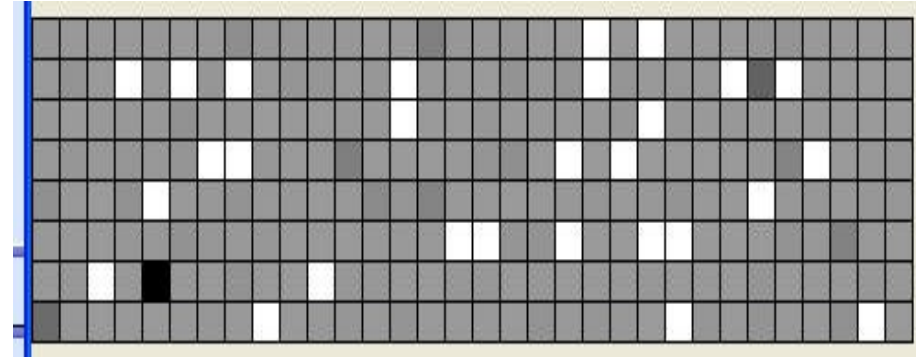
The word "Backup" is rendered in a 3D, blocky font with a green, pixelated texture. The letters are arranged in a slightly receding perspective from left to right. The 'B' is the largest, followed by 'a', 'c', 'k', 'u', and 'p'.

Fe55 source: Chip5

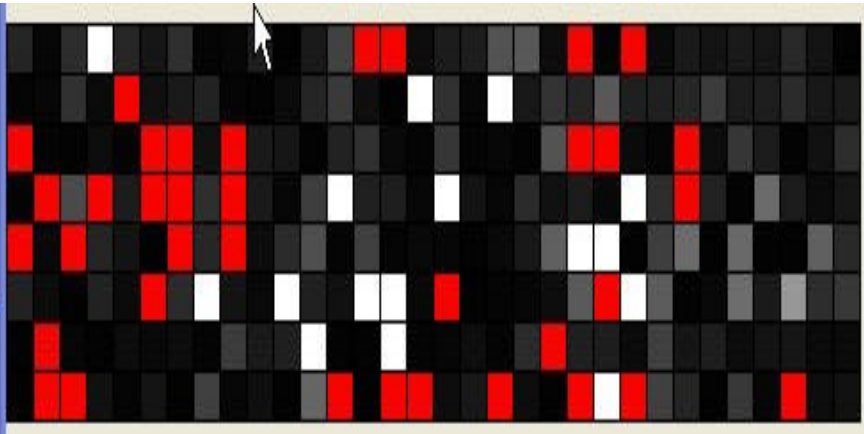
Noise scan Chip5



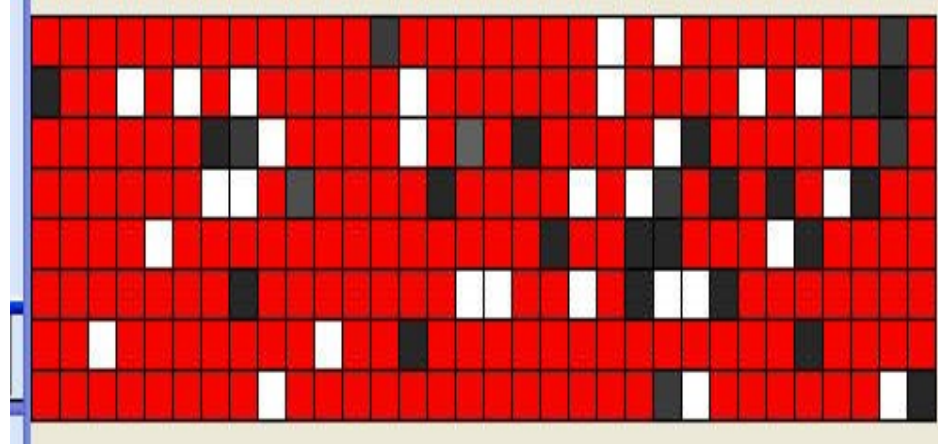
Noise scan Chip6



Fe55 at 1520
DAC Thr Chip5



Fe55 at 1477
DAC Thr Chip6

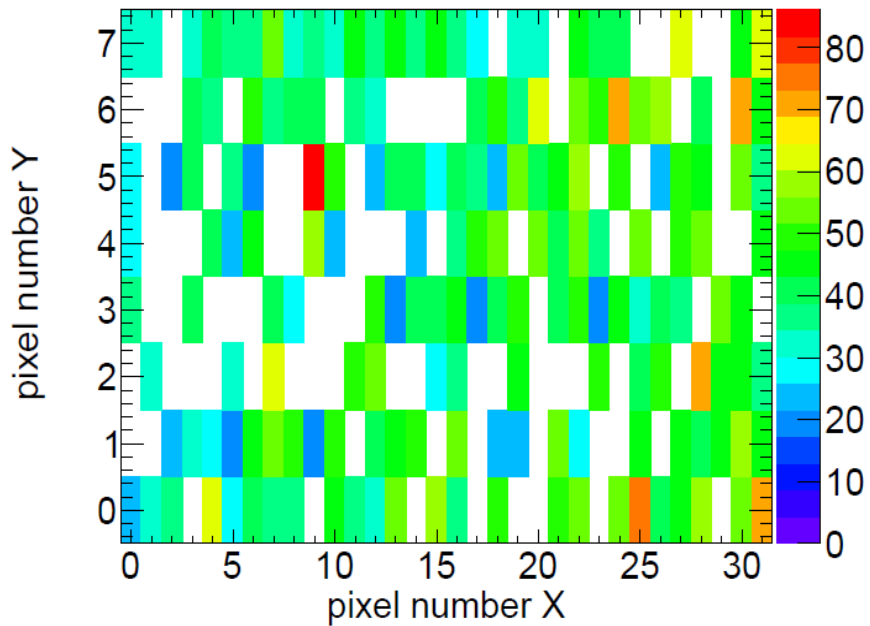


Fe55 source: Chip5 and Chip6

- For every pixel plot the maximum rate. Wants to check if source irradiates uniformly the matrix

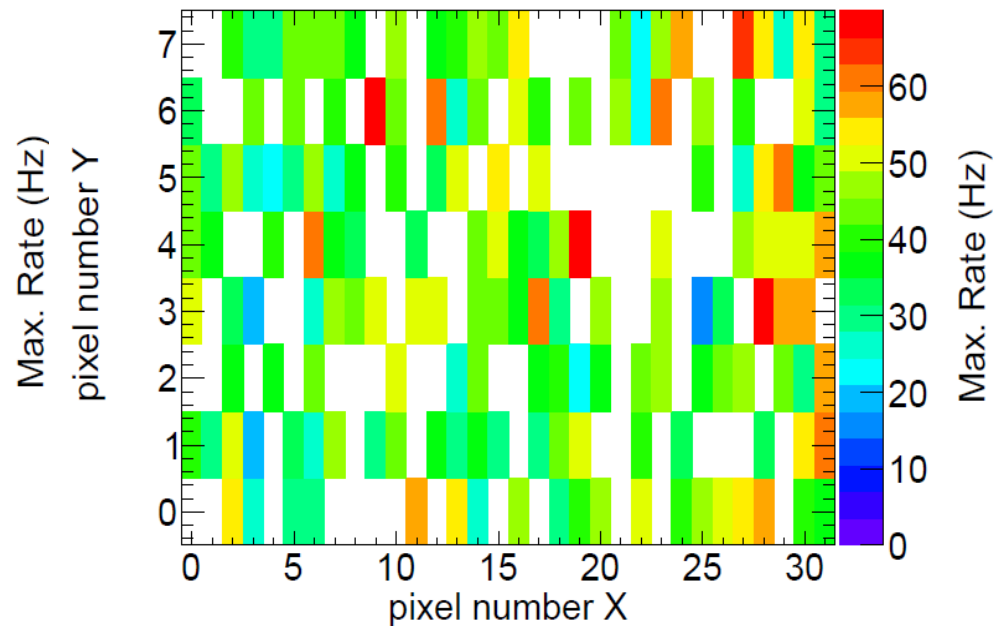
Chip5

Maximum Rate per pixel (2D)



Chip6

Maximum Rate per pixel (2D)



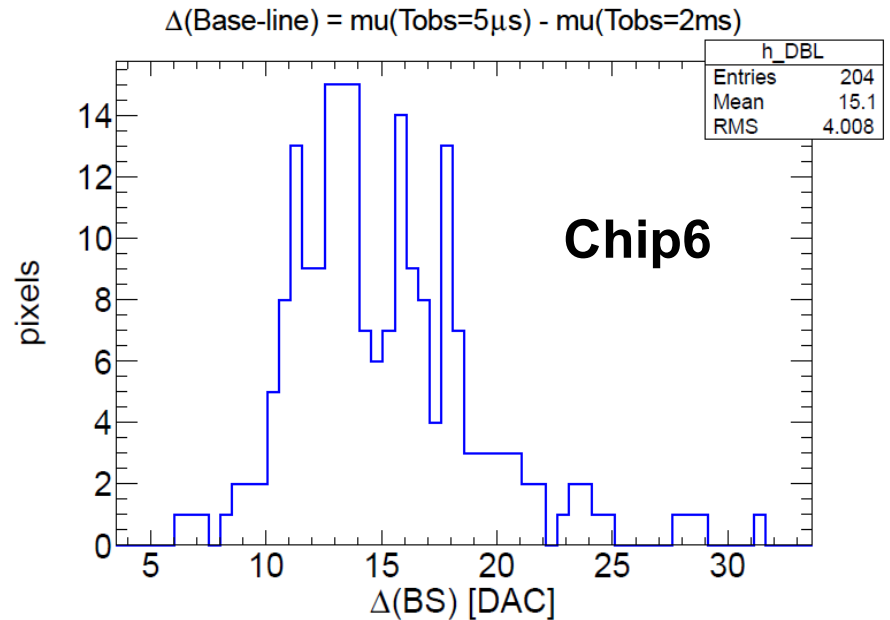
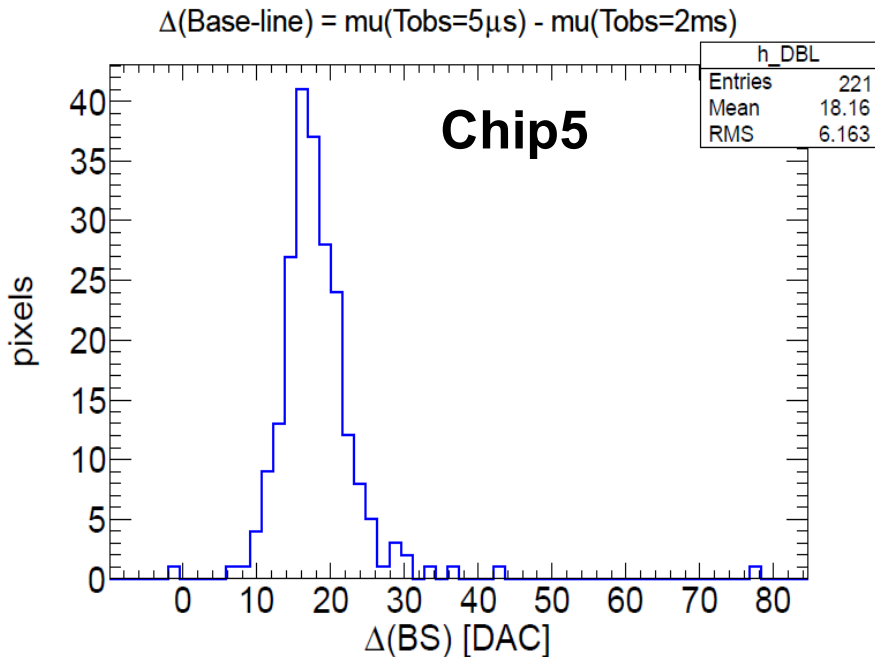
**Noise occupancy with
realistic t_{obs} ($5\mu\text{s}$)**

Realistic t_{obs} ($5\mu\text{s}$)

- Wants to evaluate what is the matrix occupancy due to noise for realistic observation times ($5\mu\text{s}$) and for different thresholds
- Also wants to have an idea of the death time as a function of the threshold
- Did noise scans from 1388 to 1504 in steps of 4 (units in DAC)
- Prediction function: use the results from the high t_{obs} (2ms) noise scans (μ, v_0, σ_R and σ_L) and scale to the current $t_{\text{obs}} \Rightarrow$ use the same noise function with the current t_{obs}
- Use this function to try to predict the occupancies for the current t_{obs} . Don't expect good description as death-time is non negligible
- Also estimate the matrix occupancy (fraction of pixel of the matrix that fired due to noise)

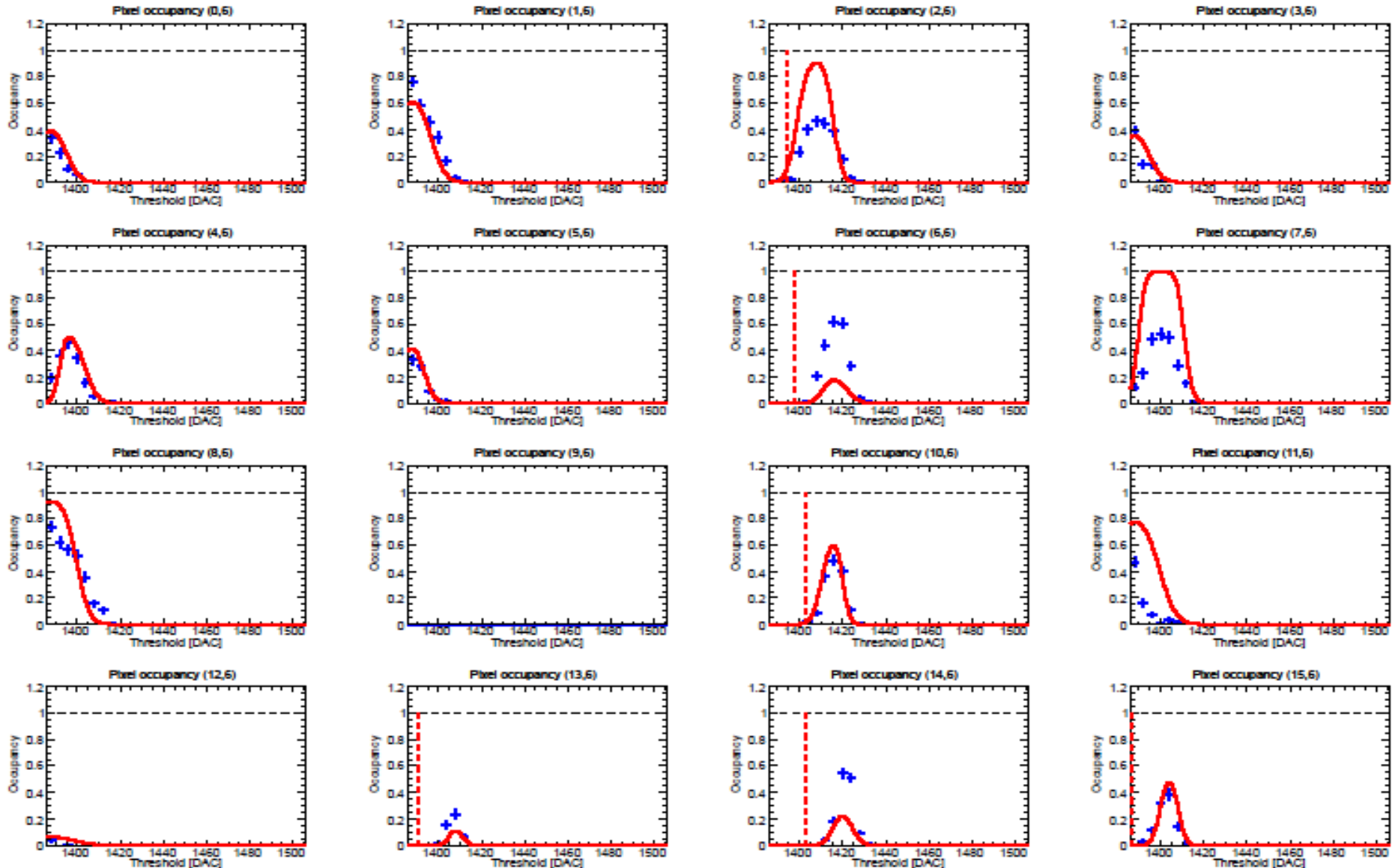
Realistic t_{obs} ($5\mu\text{s}$): variation of the base-line

- Base-line of noise scans for $t_{\text{obs}} = 5\mu\text{s}$ is different than the one for $t_{\text{obs}} = 2\text{ms}$
- Is this an effect of the temperature?
- To predict the pixel and matrix occupancy used the base-line for $t_{\text{obs}} = 5\mu\text{s}$ and the other parameters (v_0, σ_R, σ_L) extracted for the noise scans with $t_{\text{obs}} = 2\text{ms}$



Realistic t_{obs} ($5\mu s$): occupancies per pixel (Chip5)

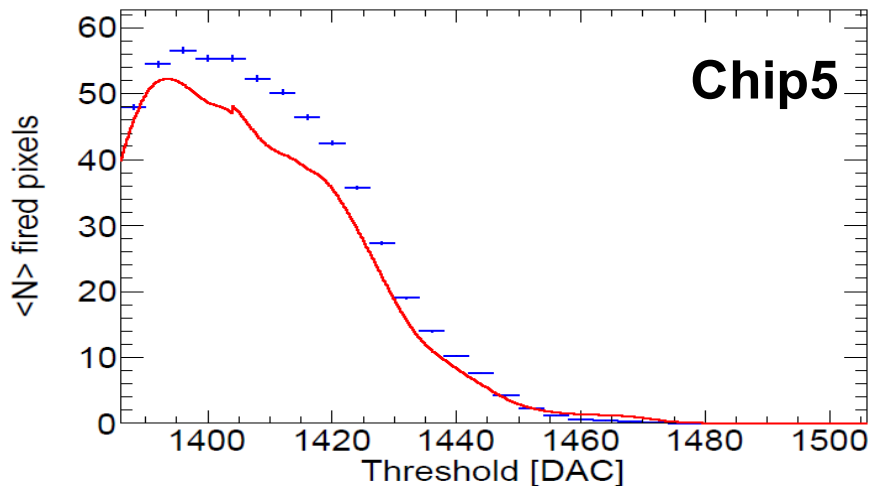
— Measurement
— Prediction



Realistic t_{obs} ($5\mu\text{s}$): matrix occupancy

- Wants to evaluate what is the matrix occupancy due to noise for realistic observation times ($5\mu\text{s}$) for different thresholds

Mean number of turned pixels



Matrix occupancy

